

## XR1008, XR2008

## 0.5mA, 75MHz Rail-to-Rail Amplifiers

#### **General Description**

The XR1008 (single) and XR2008 (dual) are rail-to-rail output amplifiers that offer superior dynamic performance with 75MHz small signal bandwidth and  $50V/\mu s$  slew rate. The XR1008 and XR2008 amplifiers consume only  $505\mu A$  of supply current per channel and are designed to operate from a supply range of 2.5V to 5.5V ( $\pm 1.25$  to  $\pm 2.75$ ).

The combination of low power, high output current drive, and rail-to-rail performance make the XR1008 and XR2008 well suited for battery-powered metering and test equipment.

The combination of low cost and high performance make these amplifiers suitable for high volume industrial applications such as ultrasonic heat meters, water meters and other applications requiring high speed and low power.

#### **FEATURES**

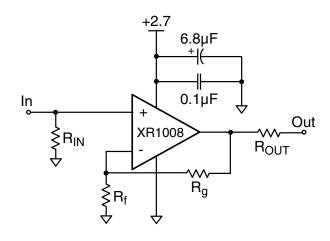
- 505µA supply current
- 75MHz bandwidth
- Input voltage range with 5V supply: -0.3V to 3.8V
- Output voltage range with 5V supply: 0.07V to 4.86V
- 50V/µs slew rate
- 12nV/JHz input voltage noise
- 15mA linear output current
- Fully specified at 2.7V and 5V supplies

#### **APPLICATIONS**

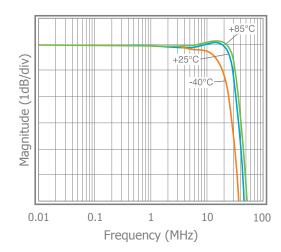
- Portable/battery-powered applications
- Mobile communications, cell phones, pagers
- ADC buffer
- Active filters
- Portable test instruments
- Signal conditioning
- Medical equipment
- Portable medical instrumentation
- Flow meters

Ordering Information - back page

## **Typical Application**



## Frequency Response vs. Temperature



## **Absolute Maximum Ratings**

Stresses beyond the limits listed below may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

V <sub>S</sub>	0V to 6V
V <sub>IN</sub>	$-V_S$ - 0.5V to $+V_S$ +0.5V
Continuous Output Current	30mA to +30mA

## **Operating Conditions**

Supply Voltage Range	2.5 to 5.5V
Operating Temperature Range	40°C to 125°C
Junction Temperature	150°C
Storage Temperature Range	65°C to 150°C
Lead Temperature (Soldering, 10s)	260°C

## **Package Thermal Resistance**

$\theta_{JA}$ (TSOT-5)	215°C/W
θ <sub>JA</sub> (SOIC-8)	150°C/W
θ <sub>JA</sub> (MSOP-8)	200°C/W
Package thermal resistance ( $\theta_{JA}$ ), JEDEC test boards, still air.	standard, multi-layer

### **ESD Protection**

XR1008 (HBM)	2kV
XR2008 (HBM)	2.5kV
ESD Rating for HBM (Human Body Model).	

## **Electrical Characteristics at +2.7V**

 $T_A$  = 25°C,  $V_S$  = +2.7V,  $R_f$  =  $R_g$  = 1k $\Omega$  ,  $R_L$  = 1k $\Omega$  to  $V_S/2;$  G = 2; unless otherwise noted.

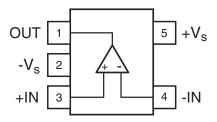
Symbol	Parameter	Conditions	Min	Тур	Max	Units	
Frequency I	Frequency Domain Response						
UGBW <sub>SS</sub>	Unity Gain -3dB Bandwidth	$G = +1, V_{OUT} = 0.05V_{pp}, R_f = 0$		65		MHz	
BW <sub>SS</sub>	-3dB Bandwidth	$G = +2, V_{OUT} < 0.2V_{pp}$		30		MHz	
BW <sub>LS</sub>	Large Signal Bandwidth	$G = +2$ , $V_{OUT} = 2V_{pp}$		12		MHz	
GBWP	Gain Bandwidth Product	$G = +11, V_{OUT} = 0.2V_{pp}$		28		MHz	
Time Doma	in Response						
t <sub>R</sub> , t <sub>F</sub>	Rise and Fall Time	V <sub>OUT</sub> = 0.2V step; (10% to 90%)		7.5		ns	
ts	Settling Time to 0.1%	V <sub>OUT</sub> = 1V step		60		ns	
OS	Overshoot	V <sub>OUT</sub> = 1V step		10		%	
SR	Slew Rate	G = -1, 2V step		40		V/µs	
Distortion/N	oise Response						
HD2	2nd Harmonic Distortion	$1MHz, V_{OUT} = 1V_{pp}$		-67		dBc	
HD3	3rd Harmonic Distortion	$1MHz$ , $V_{OUT} = 1V_{pp}$		-72		dBc	
THD	Total Harmonic Distortion	$1MHz$ , $V_{OUT} = 1V_{pp}$		65		dB	
e <sub>n</sub>	Input Voltage Noise	>10kHz		12		nV/√Hz	
DC Perform	ance						
$V_{IO}$	Input Offset Voltage			0		mV	
$d_{VIO}$	Average Drift			10		μV/°C	
I <sub>B</sub>	Input Bias Current			1.2		μΑ	
$dl_B$	Average Drift			3.5		nA/°C	
I <sub>OS</sub>	Input Offset Current			30		nA	
PSRR	Power Supply Rejection Ratio	DC	60	66		dB	
A <sub>OL</sub>	Open Loop Gain	V <sub>OUT</sub> = V <sub>S</sub> / 2		98		dB	
Is	Supply Current	per channel		470		μA	
Input Chara	cteristics						
$R_{IN}$	Input Resistance	Non-inverting		9		MΩ	
C <sub>IN</sub>	Input Capacitance			1.5		pF	
CMIR	Common Mode Input Range			-0.3 to 1.5		V	
CMRR	Common Mode Rejection Ratio	DC, $V_{CM} = 0V$ to $V_S - 1.5V$		74		dB	
Output Cha	racteristics		'			'	
V	Output Wellings Output	$R_L = 1k\Omega$ to $V_S/2$		0.09 to 2.53		V	
V <sub>OUT</sub>	Output Voltage Swing	$R_L$ = 10kΩ to $V_S$ / 2		0.05 to 2.6		V	
I <sub>OUT</sub>	Output Current			±15		mA	
I <sub>SC</sub>	Short Circuit Current			±30		mA	

## **Electrical Characteristics at +5V**

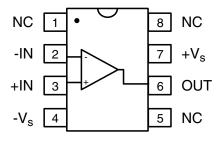
 $T_A$  = 25°C,  $V_S$  = +5V,  $R_f$  =  $R_g$  = 1k $\Omega,~R_L$  = 1k $\Omega$  to  $V_S/2;~G$  = 2; unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Units	
Frequency I	Frequency Domain Response						
UGBW <sub>SS</sub>	Unity Gain -3dB Bandwidth	$G = +1, V_{OUT} = 0.05V_{pp}, R_f = 0$		75		MHz	
BW <sub>SS</sub>	-3dB Bandwidth	$G = +2, V_{OUT} < 0.2V_{pp}$		35		MHz	
BW <sub>LS</sub>	Large Signal Bandwidth	$G = +2$ , $V_{OUT} = 2V_{pp}$		15		MHz	
GBWP	Gain Bandwidth Product	$G = +11, V_{OUT} = 0.2V_{pp}$		33		MHz	
Time Doma	in Response						
t <sub>R</sub> , t <sub>F</sub>	Rise and Fall Time	V <sub>OUT</sub> = 0.2V step; (10% to 90%)		6		ns	
ts	Settling Time to 0.1%	V <sub>OUT</sub> = 1V step		60		ns	
OS	Overshoot	V <sub>OUT</sub> = 1V step		12		%	
SR	Slew Rate	G = -1, 2V step		50		V/µs	
Distortion/N	oise Response						
HD2	2nd Harmonic Distortion	$1MHz$ , $V_{OUT} = 2V_{pp}$		-64		dBc	
HD3	3rd Harmonic Distortion	$1MHz$ , $V_{OUT} = 2V_{pp}$		-62		dBc	
THD	Total Harmonic Distortion	$1MHz$ , $V_{OUT} = 2V_{pp}$		60		dB	
e <sub>n</sub>	Input Voltage Noise	>10kHz		12		nV/√Hz	
DC Perform	ance						
$V_{IO}$	Input Offset Voltage		-5	-1	5	mV	
$d_{VIO}$	Average Drift			10		μV/°C	
I <sub>B</sub>	Input Bias Current		-3.5	1.2	3.5	μΑ	
$dl_B$	Average Drift			3.5		nA/°C	
I <sub>OS</sub>	Input Offset Current			30	350	nA	
PSRR	Power Supply Rejection Ratio	DC	60	66		dB	
A <sub>OL</sub>	Open Loop Gain	V <sub>OUT</sub> = V <sub>S</sub> / 2	65	80		dB	
Is	Supply Current	per channel		505	620	μΑ	
Input Chara	cteristics						
R <sub>IN</sub>	Input Resistance	Non-inverting		9		MΩ	
C <sub>IN</sub>	Input Capacitance			1.5		pF	
CMIR	Common Mode Input Range			-0.3 to 3.8		V	
CMRR	Common Mode Rejection Ratio	DC, $V_{CM} = 0V$ to $V_S - 1.5V$	65	74		dB	
Output Cha	racteristics	,	'	,		<u> </u>	
V	Output Veltage Cuine	$R_L = 1k\Omega$ to $V_S/2$	0.2 to 4.65	0.13 to 4.73		V	
V <sub>OUT</sub>	Output Voltage Swing	$R_L = 10k\Omega$ to $V_S / 2$		0.08 to 4.84		V	
I <sub>OUT</sub>	Output Current			±15		mA	
I <sub>SC</sub>	Short Circuit Current			±30		mA	

# XR1008 Pin Configurations TSOT-5



#### **SOIC-8**



## **XR1008 Pin Assignments**

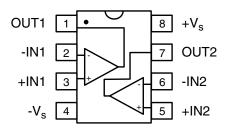
#### TSOT-5

Pin No.	Pin Name	Description
1	OUT	Output
2	-V <sub>S</sub>	Negative supply
3	+IN	Positive input
4	-IN	Negative input
5	+V <sub>S</sub>	Positive supply

#### **SOIC-8**

Pin No.	Pin Name	Description
1	NC	No Connect
2	-IN	Negative input
3	+IN	Positive input
4	-V <sub>S</sub>	Negative supply
5	NC	No Connect
6	OUT	Output
7	+V <sub>S</sub>	Positive supply
8	NC	No Connect

# XR2008 Pin Configuration SOIC-8 / MSOP-8



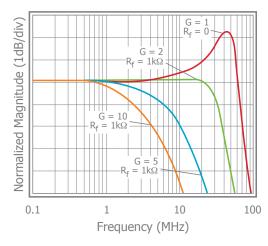
## **XR2008 Pin Assignments**

#### SOIC-8 / MSOP-8

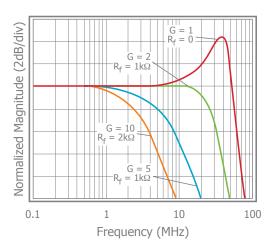
Pin No.	Pin Name	Description			
1	OUT1	Output, channel 1			
2	-IN1	Negative input, channel 1			
3	+IN1	Positive input, channel 1			
4	-V <sub>S</sub>	Negative supply			
5	+IN2	Positive input, channel 2			
6	-IN2	Negative input, channel 2			
7	OUT2	Output, channel 2			
8	+V <sub>S</sub>	Positive supply			

 $T_A$  = 25°C,  $V_S$  = +5V,  $R_f$  =  $R_q$  = 1k $\Omega$ ,  $R_L$  = 1k $\Omega$  to  $V_S/2$ ; G = 2; unless otherwise noted.

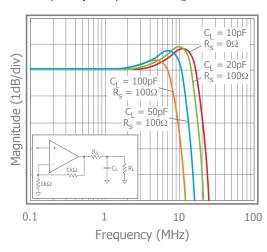
#### Non-Inverting Frequency Response at $V_S = 5V$



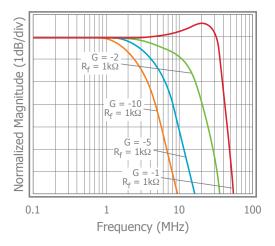
#### Non-Inverting Frequency Response at V<sub>S</sub> = 2.7V



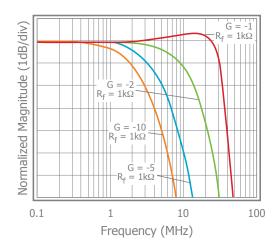
#### Frequency Response vs CL



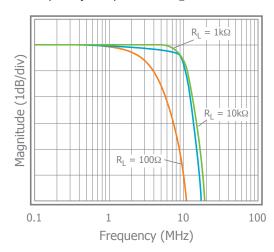
#### Inverting Frequency Response at $V_S = 5V$



#### Inverting Frequency Response at V<sub>S</sub> = 2.7V

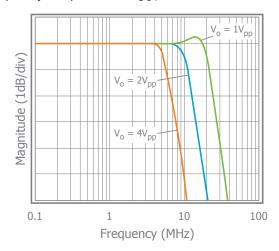


#### Frequency Response vs R<sub>L</sub>

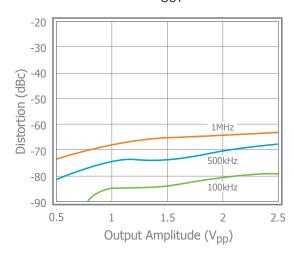


 $T_A$  = 25°C,  $V_S$  = +5V,  $R_f$  =  $R_g$  = 1k $\Omega,~R_L$  = 1k $\Omega$  to  $V_S/2;~G$  = 2; unless otherwise noted.

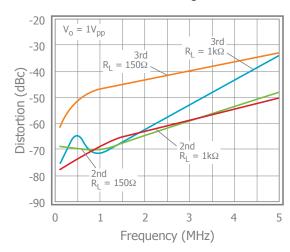
#### Frequency Response vs. VOUT



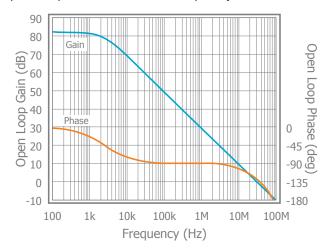
#### 2nd Harmonic Distortion vs VOUT



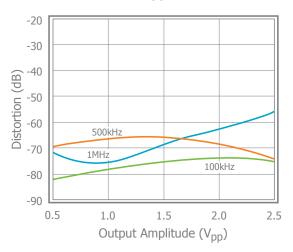
2nd & 3rd Harmonic Distortion at  $V_S = 2.7V$ 



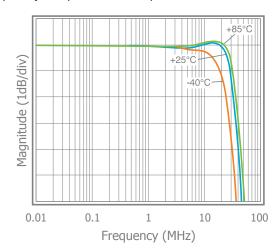
#### Open Loop Gain & Phase vs. Frequency



#### 3rd Harmonic Distortion vs VOUT

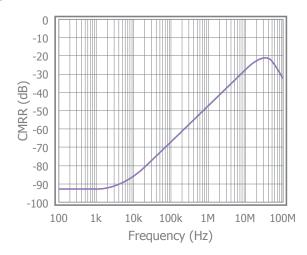


#### Frequency Response vs. Temperature

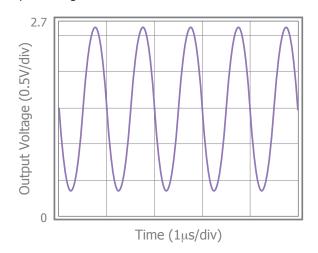


 $T_A$  = 25°C,  $V_S$  = +5V,  $R_f$  =  $R_g$  = 1k $\Omega,~R_L$  = 1k $\Omega$  to  $V_S/2;~G$  = 2; unless otherwise noted.

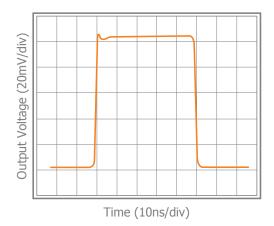
#### **CMRR**



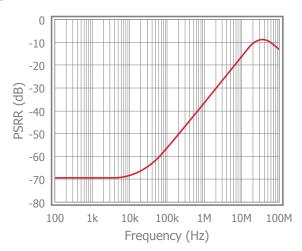
#### **Output Swing**



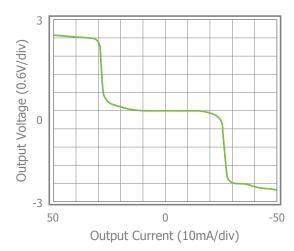
#### Small Signal Pulse Response at $V_S = 2.7V$



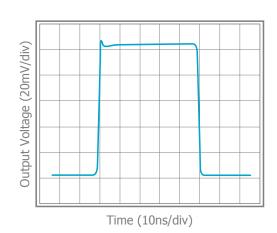
#### **PSRR**



## Output Voltage vs. Output Current

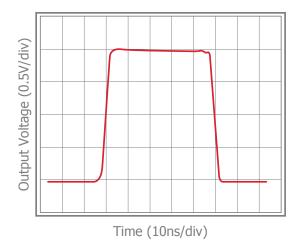


#### Small Signal Pulse Response at $V_S = 5V$

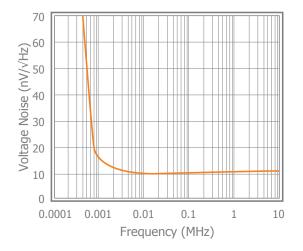


 $T_A=25^{\circ}C$ ,  $V_S=+5V$ ,  $R_f=R_g=1k\Omega$ ,  $R_L=1k\Omega$  to  $V_S/2$ ; G=2; unless otherwise noted.

Large Signal Pulse Response at  $V_S = 5V$ 



#### Input Voltage Noise



#### **Application Information**

#### **General Description**

The XR1008 family are a single supply, general purpose. voltage-feedback amplifiers fabricated on a complementary bipolar process. The XR1008 offers 75MHz unity gain bandwidth, 50V/µs slew rate, and only 505µA supply current. It features a rail-to-rail output stage and is unity gain stable.

Figures 1, 2, and 3 illustrate typical circuit configurations for non-inverting, inverting, and unity gain topologies for dual supply applications. They show the recommended bypass capacitor values and overall closed loop gain equations. Figure 4 shows the typical non-inverting gain circuit for single supply applications.

The common mode input range extends to 300mV below ground in single supply operation. Exceeding these values will not cause phase reversal. However, if the input voltage exceeds the rails by more than 0.5V, the input ESD devices will begin to conduct.

The design uses a Darlington output stage. The output stage is short circuit protected and offers "soft" saturation protection that improves recovery time.

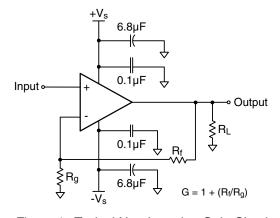


Figure 1: Typical Non-Inverting Gain Circuit

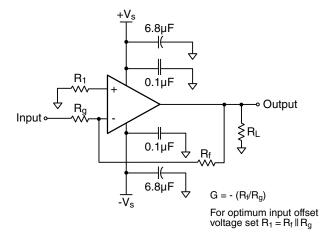


Figure 2: Typical Inverting Gain Circuit

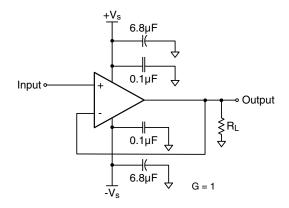


Figure 3: Unity Gain Circuit

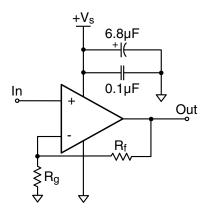


Figure 4: Single Supply Non-Inverting Gain Circuit

For optimum response at a gain of +2, a feedback resistor of  $1k\Omega$  is recommended. Figure 5 illustrates the XR1008 frequency response with both  $1k\Omega$  and  $2k\Omega$  feedback resistors.

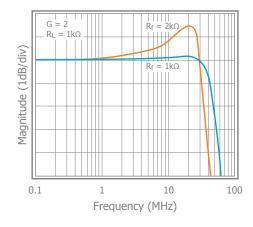


Figure 5: Frequency Response vs. Rf

#### **Power Dissipation**

Power dissipation should not be a factor when operating under the stated  $1k\Omega$  load condition. However, applications with low impedance, DC coupled loads should be analyzed to ensure that maximum allowed junction temperature is not exceeded. Guidelines listed below can be used to verify that the particular application will not cause the device to operate beyond it's intended operating range.

Maximum power levels are set by the absolute maximum junction rating of 150°C. To calculate the junction temperature, the package thermal resistance value Theta $_{JA}$  ( $\theta_{JA}$ ) is used along with the total die power dissipation.

$$T_{Junction} = T_{Ambient} + (\theta_{JA} \times P_D)$$

Where T<sub>Ambient</sub> is the temperature of the working environment.

In order to determine  $P_D$ , the power dissipated in the load needs to be subtracted from the total power delivered by the supplies.

$$P_D = P_{supply} - P_{load}$$

Supply power is calculated by the standard power equation.

$$P_{\text{supply}} = V_{\text{supply}} \times I_{\text{RMSsupply}}$$
 $V_{\text{supply}} = V_{\text{S+}} - V_{\text{S-}}$ 

Power delivered to a purely resistive load is:

$$P_{load} = ((V_{load})_{RMS^2})/Rload_{eff}$$

The effective load resistor (Rload<sub>eff</sub>) will need to include the effect of the feedback network. For instance,

Rload<sub>eff</sub> in Figure 3 would be calculated as:

$$R_L \parallel (R_f + R_a)$$

These measurements are basic and are relatively easy to perform with standard lab equipment. For design purposes however, prior knowledge of actual signal levels and load impedance is needed to determine the dissipated power. Here,  $P_{\rm D}$  can be found from

$$P_D = P_{Ouiescent} + P_{Dynamic} - P_{load}$$

Quiescent power can be derived from the specified  $I_S$  values along with known supply voltage,  $V_{\text{supply}}$ . Load power can be calculated as above with the desired signal amplitudes using:

$$(V_{load})_{RMS} = V_{peak} / \sqrt{2}$$

$$(I_{load})_{RMS} = (V_{load})_{RMS} / Rload_{eff}$$

The dynamic power is focused primarily within the output stage driving the load. This value can be calculated as:

$$P_{Dynamic} = (V_{S+} - V_{load})_{RMS} \times (I_{load})_{RMS}$$

Assuming the load is referenced in the middle of the power rails or  $V_{\text{supply}}/2$ .

The XR1008 is short circuit protected. However, this may not guarantee that the maximum junction temperature (+150°C) is not exceeded under all conditions. Figure 6 shows the maximum safe power dissipation in the package vs. the ambient temperature for the packages available.

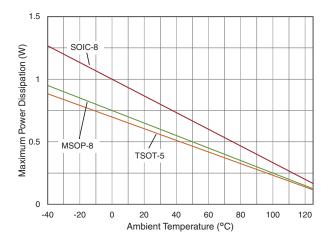


Figure 6. Maximum Power Derating

### **Driving Capacitive Loads**

Increased phase delay at the output due to capacitive loading can cause ringing, peaking in the frequency response, and possible unstable behavior. Use a series resistance,  $R_S$ , between the amplifier and the load to help improve stability and settling performance. Refer to Figure 7.

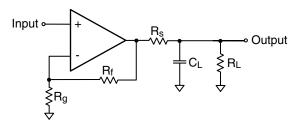


Figure 7. Addition of R<sub>S</sub> for Driving Capacitive Loads

Table 1 provides the recommended  $R_S$  for various capacitive loads. The recommended  $R_S$  values result in approximately <1dB peaking in the frequency response.

C <sub>L</sub> (pF)	R <sub>S</sub> (Ω)	-3dB BW (MHz)
10pF	0	22
20pF	100	19
50pF	100	12
100pF	100	10.2

Table 1: Recommended R<sub>S</sub> vs. C<sub>L</sub>

For a given load capacitance, adjust  $R_{\rm S}$  to optimize the tradeoff between settling time and bandwidth. In general, reducing  $R_{\rm S}$  will increase bandwidth at the expense of additional overshoot and ringing.

#### **Overdrive Recovery**

For an amplifier, an overdrive condition occurs when the output and/or input ranges are exceeded. The recovery time varies based on whether the input or output is overdriven and by how much the ranges are exceeded. The XR1008, and XR2008 will typically recover in less than 20ns from an overdrive condition. Figure 5 shows the XR1008 in an overdriven condition.

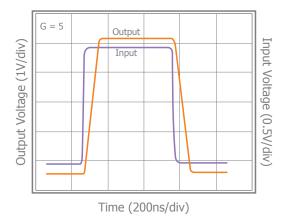


Figure 8: Overdrive Recovery

#### **Layout Considerations**

General layout and supply bypassing play major roles in high frequency performance. Exar has evaluation boards to use as a guide for high frequency layout and as an aid in device testing and characterization. Follow the steps below as a basis for high frequency layout:

- Include 6.8µF and 0.1µF ceramic capacitors for power supply decoupling
- Place the 6.8µF capacitor within 0.75 inches of the power pin
- Place the 0.1µF capacitor within 0.1 inches of the power pin
- Remove the ground plane under and around the part, especially near the input and output pins to reduce parasitic capacitance
- Minimize all trace lengths to reduce series inductances

Refer to the evaluation board layouts below for more information.

#### **Evaluation Board Information**

The following evaluation boards are available to aid in the testing and layout of these devices:

Evaluation Board #	Products
CEB002	XR1008 in TSOT
CEB003	XR1008 in SOIC
CEB006	XR2008 in SOIC
CEB010	XR2008 in MSOP

#### **Evaluation Board Schematics**

Evaluation board schematics and layouts are shown in Figures 9-18 These evaluation boards are built for dual-supply operation. Follow these steps to use the board in a single-supply application:

- 1. Short -V<sub>S</sub> to ground.
- 2. Use C3 and C4, if the -V  $_{S}$  pin of the amplifier is not directly connected to the ground plane.

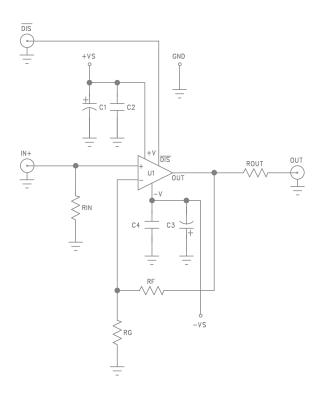


Figure 9. CEB002 & CEB003 Schematic

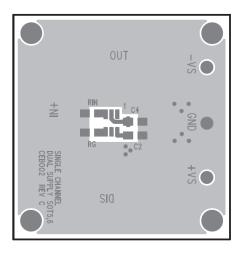


Figure 10. CEB002 Top View

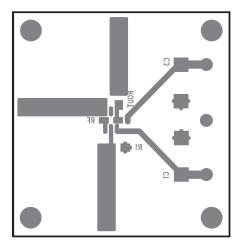


Figure 11. CEB002 Bottom View

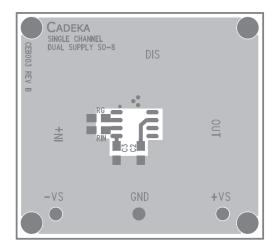


Figure 12. CEB003 Top View

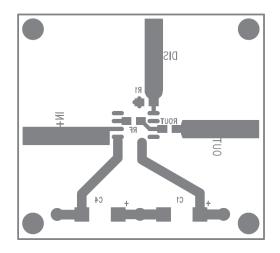


Figure 13. CEB003 Bottom View

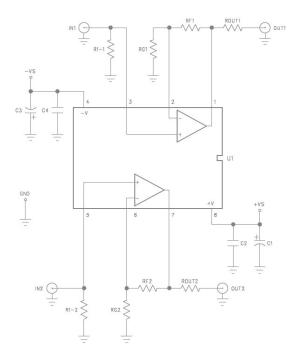


Figure 14. CEB006 & CEB010 Schematic

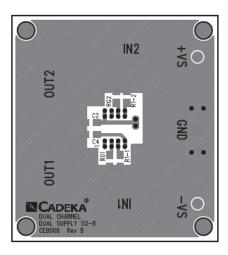


Figure 15. CEB006 Top View

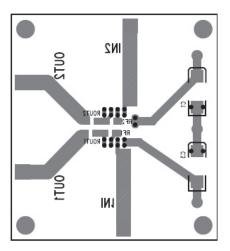


Figure 16. CEB006 Bottom View

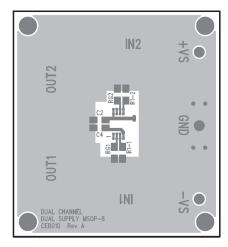


Figure 17. CEB010 Top View

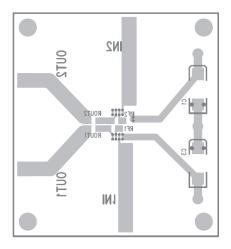
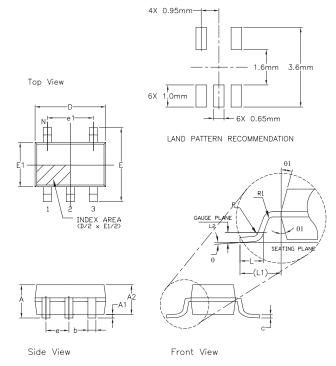


Figure 18. CEB010 Bottom View

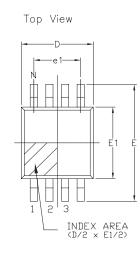
## **Mechanical Dimensions**

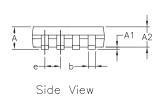
## **TSOT-5 Package**



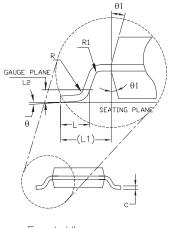
5 Pin TSOT (OPTION 2)						
SYMBOLS	DIMENSION IN MM (Control Unit)				SION IN erence	
	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.75	_	0.80	0.030	_	0.031
A1	0.00	_	0.05	0.000	_	0.002
A2	0.70	0.75	0.78	0.028	0.030	0.031
b	0.35	_	0.50	0.012	_	0.020
С	0.10	_	0.20	0.003	_	0.008
D	2	.90 BS	SC .	(	).114 B	sc
E	2.80 BSC 0.110 BSC		sc			
E1	1	.60 BS	SC .	(	.063 B	SC
е	(	.95 BS	SC .	(	.038 B	sc
e1	1	.90 BS	SC .	(	.075 B	sc
L	0.37	0.45	0.60	0.012	0.018	0.024
L1		).60 RE	F	0	.024 RE	F
L2	(	).25 BS	SC .	0	.010 BS	iC .
R	0.10	—	_	0.004	_	_
R1	0.10	_	0.25	0.004	_	0.010
θ	0,	4*	8.	0,	4*	8*
θ1	4°	10°	12*	4*	10°	12°
N	5 5					

#### **MSOP-8 Package**





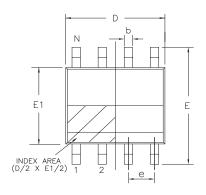
8 Pin	MSOP	JEDEO	MO-	187 V	'ariatio	n AA
SYMBOLS	DIMENSIONS IN MM (Control Unit)			DIMENSIONS IN INCH (Reference Unit)		
	MIN	NOM	MAX	MIN	NOM	MAX
Α	_	_	1.10	_	_	0.043
A1	0.00		0.15	0.000	_	0.006
A2	0.75	0.85	0.95	0.030	0.033	0.037
b	0.22	_	0.38	0.009	_	0.015
С	0.08	_	0.23	0.003	_	0.009
Е	4.90 BSC			0.193 BSC		
E1	3.00 BSC			0.118 BSC		
e	0.65 BSC			0.026 BSC		
e1	1.95 BSC			0.077 BSC		
٦	0.40 0.60		0.80	0.016	0.024	0.031
L1	0.95 REF			0.037 REF		
L2	0.25 BSC			0.010 BSC		
R	0.07	_	1	0.003	_	_
R1	0.07	_	_	0.003	_	_
θ	0.	_	8.	0.	_	8*
θ1	5*	-	15°	5*	_	15*
D	3.00 BSC			0.118 BSC		
N	8				8	



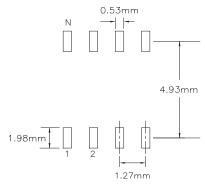
Front View

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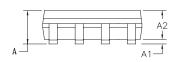
## **SOIC-8 Package**



RECOMMENDED PCB LAND PATTERN



Top View



θ CAUGE PLANE

SEATING PLANE

(L1)

L2

Side View

Front View

8 Pin	SOICN	JEDE	EC MS-	-012	Variatio	n AA
SYMBOLS	DIMENSIONS IN MM (Control Unit)			DIMENSIONS IN INCH (Reference Unit)		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.35	_	1.75	0.053	_	0.069
A1	0.10	_	0.25	0.004	_	0.010
A2	1.25		1.65	0.049		0.065
ь	0.31	_	0.51	0.012		0.020
С	0.17	_	0.25	0.007	_	0.010
E	6.00 BSC			0.236 BSC		
E1	3.90 BSC			0.154 BSC		
e	1.27 BSC			0.050 BSC		
h	0.25	_	0.50	0.010	_	0.020
L	0.40	_	1.27	0.016	_	0.050
L1	1.04 REF			0.041 REF		
L2	0.25 BSC			0.010 BSC		
R	0.07	_	_	0.003	_	_
R1	0.07	_	_	0.003	_	_
θ	0.	_	8.	0.	_	8.
θ1	5*	_	15°	5*	_	15°
θ2	0. —		_	0,	_	_
D	4.90 BSC			0.193 BSC		
N	8			8		

#### **Ordering Information**

Part Number	Package	Green	Operating Temperature Range	Packaging Quantity	Marking	
XR1008 Ordering Information						
XR1008IST5X	TSOT-5	Yes	-40°C to +125°C	2.5k Tape & Reel	TC	
XR1008IST5MTR	TSOT-5	Yes	-40°C to +125°C	250 Tape & Reel	TC	
XR1008IST5EVB	Evaluation Board	N/A	N/A	N/A	N/A	
XR1008ISO8X	SOIC-8	Yes	-40°C to +125°C	2.5k Tape & Reel	XR1008	
XR1008ISO8MTR	SOIC-8	Yes	-40°C to +125°C	250 Tape & Reel	XR1008	
XR1008ISO8EVB	Evaluation Board	N/A	N/A	N/A	N/A	
XR2008 Ordering Information						
XR2008ISO8X	SOIC-8	Yes	-40°C to +125°C	2.5k Tape & Reel	XR2008	
XR2008ISO8MTR	SOIC-8	Yes	-40°C to +125°C	250 Tape & Reel	XR2008	
XR2008ISO8EVB	Evaluation Board	N/A	N/A	N/A	N/A	
XR2008IMP8X	MSOP-8	Yes	-40°C to +125°C	2.5k Tape & Reel	2008	
XR2008IMP8MTR	MSOP-8	Yes	-40°C to +125°C	250 Tape & Reel	2008	
XR2008IMP8EVB	Evaluation Board	N/A	N/A	N/A	N/A	

Moisture sensitivity level for all parts is MSL-1.

#### **Revision History**

Revision	Date	Description
1A	June 2014	Initial Release [ECN1426-09 I 6/24/14]
1B	Sept 2014	Added XR1008 ESD, increased operating temperature range, updated package outline drawings, and removed Preliminary note on XR1008. [ECN1436-02   9/4/14

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 $\textbf{Email:} \ \underline{CustomerSupport@exar.com} \ or \ \underline{HPATechSupport@exar.com}$ 

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